

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1300	(438/778).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
L2	328	(438/775).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
L3	4365	(438/396).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
L4	278	(438/399).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
S1	106	ti same atomic adj layer adj deposition and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 20:32
S2	20	ti same atomic adj layer adj deposition and capacitor and bottom adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/26 23:23
S3	11	ti same atomic adj layer adj deposition and capacitor and nh\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/26 23:24
S4	55	ti same atomic adj layer adj deposition and "nh.sub.3" and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/26 23:26
S5	39	ti same atomic adj layer adj deposition and "nh.sub.3" and electrode and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/26 23:28

S6	58	ald with tin and "nh.sub.3" and electrode and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/26 23:28
S7	5	ald near tin and "nh.sub.3" and electrode and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/26 23:34
S8	4	ald near tin and "nh.sub.3" and electrode and capacitor and nitrid\$9 same dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:34
S10	0	ald near tin and "nh.sub.3" and electrode and capacitor and nitridiz\$6 with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:34
S11	0	ald near tin and "nh.sub.3" and nitridiz\$6 with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:34
S12	6	ald and "nh.sub.3" and nitridiz\$6 with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:35
S13	6	ald and "nh.sub.3" and nitridiz\$6 with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:43
S14	0	ald and ammonia and nitridiz\$6 with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:42
S16	130	ald and "nh.sub.3" and nitrid\$8 with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:43
S17	51	ald with tin and "nh.sub.3" and nitrid\$8 with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:43

S18	8	ald near tin and "nh.sub.3" and nitrid\$8 with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:05
S19	13	ald near tin and "nh.sub.3" and nitrid\$8 same dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 00:57
S20	0	("6,489,2146,518,6346,551,3996, 551,8736,551,8936,573,547").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/27 00:58
S21	12	(("6,489,214") or ("6,518,634") or ("6,551,399") or ("6,551,873") or ("6,551,893") or ("6,573,547")). PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/27 00:58
S22	0	ald near tin and "nh.sub.3" and nitridation with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:06
S23	0	ald near tin and "nh.sub.3" and nitridations same dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:06
S24	52	ald and "nh.sub.3" and nitridations same dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:06
S25	22	ald and "nh.sub.3" and nitridations same dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:06
S26	22	ald and "nh.sub.3" and nitridation same dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:06
S27	10	ald with tin and "nh.sub.3" and nitridation same dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:13

S28	11	ald and "nh.sub.3" and nitridation with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 13:03
S29	11	ald and "nh.sub.3" and (nitridation or nitrify) with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:18
S30	779	438/785	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:20
S32	272	(438/775).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
S34	3	ald adj tin and nitridation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:23
S35	4	ald near tin and nitridation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:23
S36	32	ald with tin and nitridation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/18 20:14
S37	2	ald with tin and nitridation with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:24
S38	20	"6225168"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 01:24
S39	3	ald with tin and nitriding with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 20:30

S40	4156	(438/396).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
S41	221	(438/399).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47
S42	52	kim-young-soo.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/27 20:33
S46	8	ald and ammonia and nitrid\$6 with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/18 20:11
S47	537	ald and ti and nitrid\$6 same dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/18 20:14
S48	204	ald and ti and nitrid\$6 same dielectric and "nh.sub.3"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/18 20:15
S49	62	ald and ti and nitrid\$6 same dielectric and "nh.sub.3" near gas	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/18 20:15
S50	34	ald and ti and nitrid\$6 same dielectric and "nh.sub.3" near gas and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/18 20:18
S51	3	ald and ti and nitriding same dielectric and "nh.sub.3" near gas and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 11:24
S52	420	(438/791).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 16:47

S53	47	S52 and ti	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 11:36
S54	258	nitridation same dielectric and ti	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 11:28
S55	34	nitridation near4 dielectric and ti	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 11:28
S56	4	nitridation near4 dielectric and ti and ald	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 12:41
S57	16	S52 and ti and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 11:46
S58	1	S52 and ti and capacitor and ald	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 11:46
S59	16	nitridation near8 dielectric and ti and ald	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 12:41
S60	5	ald near tin and "nh. <sub>3</sub> " and electrode and capacitor and nitrid\$9 with dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 12:57
S61	22	ald adj tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 13:03
S62	29	ald and ("nh. <sub>3</sub> " or ammonia) and nitridation with dielectric and tin	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 13:04